# LTC5541



# FEATURES

- Conversion Gain: 7.8dB at 1950MHz
- IIP3: 26.4dBm at 1950MHz
- Noise Figure: 9.6dB at 1950MHz
- 16dB NF Under +5dBm Blocking
- High Input P1dB
- 3.3V Supply, 630mW Power Consumption
- Shutdown Pin
- 50Ω Single-Ended RF and LO Inputs
- LO Inputs 50Ω Matched when Shutdown
- High Isolation LO Switch
- OdBm LO Drive Level
- High LO-RF and LO-IF Isolation
- Small Solution Size
- 20-Lead (5mm × 5mm) QFN package

# **APPLICATIONS**

- Wireless Infrastructure Receivers (LTE, W-CDMA, TD-SCDMA, UMTS, GSM1800)
- Point-To-Point Microwave Links
- High Dynamic Range Downmixer Applications

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## 1.3GHz to 2.3GHz High Dynamic Range Downconverting Mixer **DESCRIPTION**

The LTC<sup>®</sup>5541 is part of a family of high dynamic range passive, high gain downconverting mixers covering the 600MHz to 4GHz frequency range. **The LTC5541 is optimized for 1.3GHz to 2.3GHz RF applications. The LO frequency must fall within the 1.4GHz to 2.0GHz range for optimum performance.** A typical application is a LTE or W-CDMA receiver with a 1.7GHz to 2.2GHz RF input and low-side LO.

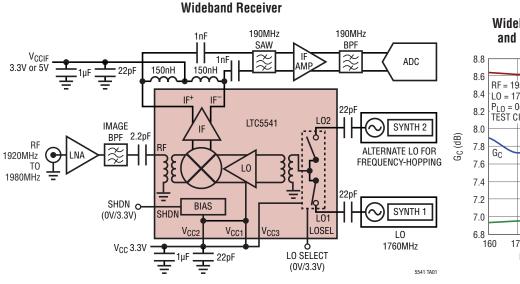
The LTC5541 is designed for 3.3V operation, however; the IF amplifier can be powered by 5V for the highest P1dB. An integrated SPDT LO switch with fast switching accepts two active LO signals, while providing high isolation.

The LTC5541's high conversion gain and high dynamic range enable the use of lossy IF filters in high-selectivity receiver designs, while minimizing the total solution cost, board space and system-level variation.

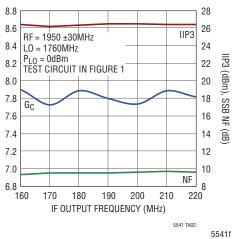
#### High Dynamic Range Downconverting Mixer Family

3 7		,
PART#	RF RANGE	LO RANGE
LTC5540	600MHz –1.3GHz	700MHz – 1.2GHz
LTC5541	1.3GHz – 2.3GHz	1.4GHz – 2.0GHz
LTC5542	1.6GHz – 2.7GHz	1.7GHz – 2.5GHz
LTC5543	2.3GHz – 4GHz	2.4GHz – 3.6GHz

# TYPICAL APPLICATION



#### Wideband Conversion Gain, IIP3 and NF vs IF Output Frequency



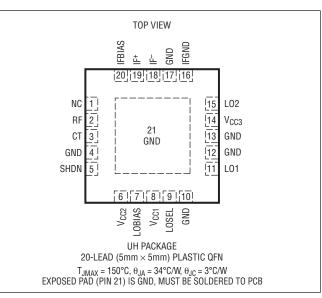


# **ABSOLUTE MAXIMUM RATINGS**

#### (Note 1)

Mixer Supply Voltage (V <sub>CC1</sub> , V <sub>CC2</sub> ) LO Switch Supply Voltage (V <sub>CC3</sub> )	
IF Supply Voltage (IF <sup>+</sup> , IF <sup>-</sup> )	
Shutdown Voltage (SHDN)–0.3V to $V_{CC}$ +	
LO Select Voltage (LOSEL)0.3V to V <sub>CC</sub> -	
LO1, LO2 Input Power (1GHz to 3GHz)	9dBm
LO1, LO2 Input DC Voltage	±0.5V
RF Input Power (1GHz to 3GHz)15	ōdBm
RF Input DC Voltage	
Operating Temperature Range40°C to	85°C
Storage Temperature Range65°C to 1	50°C
Junction Temperature (T <sub>J</sub> ) 1	50°C

# PIN CONFIGURATION



# ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTC5541IUH#PBF	LTC5541IUH#TRPBF	5541	20-Lead (5mm x 5mm) Plastic QFN	–40°C to 85°C

Consult LTC Marketing for parts specified with wider operating temperature ranges. Consult LTC Marketing for information on non-standard lead based finish parts.

For more information on lead free part marking, go to: http://www.linear.com/leadfree/ For more information on tape and reel specifications, go to: http://www.linear.com/tapeandreel/

# **AC ELECTRICAL CHARACTERISTICS** $V_{CC} = 3.3V$ , $V_{CCIF} = 3.3V$ , SHDN = Low, $T_A = 25^{\circ}C$ , $P_{LO} = 0dBm$ ,

unless otherwise noted. Test circuit shown in Figure 1. (Notes 2, 3, 4)
PARAMETER
CONDITIONS

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
LO Input Frequency Range			1400 to 2000		MHz
RF Input Frequency Range	Low-Side LO High-Side LO		1600 to 2300 1300 to 1800		MHz MHz
IF Output Frequency Range	Requires External Matching		5 to 500		MHz
RF Input Return Loss	Z <sub>0</sub> = 50Ω, 1300MHz to 2300MHz		>12		dB
LO Input Return Loss	Z <sub>0</sub> = 50Ω, 1400MHz to 2000MHz		>12		dB
IF Output Return Loss	Requires External Matching		>12		dB
LO Input Power	f <sub>L0</sub> = 1400MHz to 2000MHz	-4	-4 0 6		dBm
LO to RF Leakage	f <sub>L0</sub> = 1400MHz to 2000MHz		<-32		dBm
LO to IF Leakage	f <sub>L0</sub> = 1400MHz to 2000MHz		<-31		dBm
LO Switch Isolation	L01 Selected, 1400MHz < $f_{L0}$ < 2000MHz L02 Selected, 1400MHz < $f_{L0}$ < 2000MHz		52 50		dB dB
RF to LO Isolation	f <sub>RF</sub> = 1300MHz to 2300MHz		>52		dB
RF to IF Isolation	f <sub>RF</sub> = 1300MHz to 2300MHz		>33		dB
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**AC ELECTRICAL CHARACTERISTICS**  $V_{CC} = 3.3V$ ,  $V_{CCIF} = 3.3V$ , SHDN = Low,  $T_A = 25^{\circ}C$ ,  $P_{L0} = 0dBm$ ,  $P_{RF} = -3dBm$  ( $\Delta f = 2MHz$  for two-tone IIP3 tests),unless otherwise noted. Test circuit shown in Figure 1. (Notes 2, 3, 4)

Low-Side LO Downmixer Application: RF =	1700 to 2200MHz, IF = 190MHz, $f_{LO} = f_{RF} - f_{IF}$
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PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
Conversion Gain	RF = 1750MHz RF = 1950MHz RF = 2150MHz	6.5	8.6 7.8 7.6		dB
Conversion Gain Flatness	RF = 1950 ±30MHz, LO = 1760MHz, IF=190 ±30MHz		±0.1		dB
Conversion Gain vs Temperature	$T_A = -40^{\circ}C$ to +85°C, RF = 1950MHz		-0.006		dB/°C
Input 3 <sup>rd</sup> Order Intercept	RF = 1750MHz RF = 1950MHz RF = 2150MHz	24.0	25.5 26.4 25.5		dBm
SSB Noise Figure	RF = 1750MHz RF = 1950MHz RF = 2150MHz		9.2 9.6 10.6	11.7	dB
SSB Noise Figure Under Blocking	$f_{\text{RF}}$ = 1950MHz, $f_{\text{LO}}$ = 1760MHz, $f_{\text{BLOCK}}$ = 2050MHz, $P_{\text{BLOCK}}$ = 5dBm		16		dB
$2RF - 2LO$ Output Spurious Product ( $f_{RF} = f_{LO} + f_{IF}/2$ )	$f_{RF} = 1855MHz \text{ at } -10dBm, f_{LO} = 1760MHz, f_{IF} = 190MHz$		-67		dBc
$3RF - 3LO$ Output Spurious Product $(f_{RF} = f_{LO} + f_{IF}/3)$	f <sub>RF</sub> = 1823.33MHz at -10dBm, f <sub>LO</sub> = 1760MHz, f <sub>IF</sub> = 190MHz	-73			dBc
Input 1dB Compression	RF = 1950MHz, V <sub>CCIF</sub> = 3.3V RF = 1950MHz, V <sub>CCIF</sub> = 5V		11.3 14.6		dBm
High-Side LO Downmixer Application: RF	= 1300-1800MHz, IF = 190MHz, f <sub>L0</sub> = f <sub>RF</sub> +f <sub>IF</sub>				
PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
Conversion Gain	RF = 1450MHz RF = 1600MHz RF = 1750MHz		8.9 8.4 8.0		dB
Conversion Gain Flatness	RF = 1600MHz ±30MHz, LO = 1790MHz, IF = 190 ±30MHz		±0.1		dB
Conversion Gain vs Temperature	T <sub>A</sub> = -40°C to 85°C, RF = 1600MHz		-0.006		dB/°C
Input 3rd Order Intercept	RF = 1450MHz RF = 1600MHz RF = 1750MHz		24.5 24.6 24.3		dBm
SSB Noise Figure	RF = 1450MHz RF = 1600MHz RF = 1750MHz	9.5 9.9 9.9		dB	
SSB Noise Figure Under Blocking	$f_{RF}$ = 1600MHz, $f_{LO}$ = 1790MHz, $f_{IF}$ = 190MHz $f_{BLOCK}$ = 1500MHz, $P_{BLOCK}$ = 5dBm		18		dB
$\frac{2LO-2RF \ Output \ Spurious \ Product}{(f_{RF}=f_{LO}-f_{IF/2})}$	$f_{RF} = 1695MHz \text{ at } -10dBm, f_{LO} = 1790MHz$ $f_{IF} = 190MHz$ -69			dBc	
$3LO - 3RF$ Output Spurious Product $(f_{RF} = f_{LO} - f_{IF/3})$	f <sub>RF</sub> = 1726.67MHz at –10dBm, f <sub>LO</sub> = 1790MHz f <sub>IF</sub> = 190MHz				dBc
Input 1dB Compression	RF = 1750MHz, V <sub>CCIF</sub> = 3.3V         11.1           RF = 1750MHz, V <sub>CCIF</sub> = 5V         14.4				dBm

### DC ELECTRICAL CHARACTERISTICS

noted. Test circuit shown in Figure 1. (Note 2)

 $V_{CC}$  = 3.3V,  $V_{CCIF}$  = 3.3V, SHDN = Low,  $T_A$  = 25°C, unless otherwise

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Power Supply Requirements ( $V_{CC}$ , $V_{CCIF}$ )		,			
V <sub>CC</sub> Supply Voltage (Pins 6, 8 and 14)		3.1	3.3	3.5	V
V <sub>CCIF</sub> Supply Voltage (Pins 18 and 19)		3.1	3.3	5.3	V
V <sub>CC</sub> Supply Current (Pins 6 + 8 + 14) V <sub>CCIF</sub> Supply Current (Pins 18 + 19) Total Supply Current (V <sub>CC</sub> + V <sub>CCIF</sub> )			92 100 192	108 120 228	mA
Total Supply Current – Shutdown	SHDN = High			500	μA
Shutdown Logic Input (SHDN) Low = On, Hi	gh = Off				
SHDN Input High Voltage (Off)		3			V
SHDN Input Low Voltage (On)				0.3	V
SHDN Input Current	-0.3V to V <sub>CC</sub> + 0.3V	-20		30	μA
Turn On Time			1		μs
Turn Off Time			1.5		μs
LO Select Logic Input (LOSEL) Low = LO1 S	elected, High = LO2 Selected	÷			
LOSEL Input High Voltage		3			V
LOSEL Input Low Voltage				0.3	V
LOSEL Input Current	-0.3V to V <sub>CC</sub> + 0.3V	-20		30	μA
LO Switching Time			50		ns

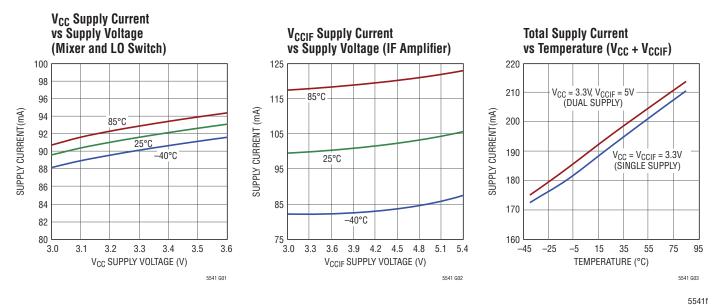
**Note 1:** Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

**Note 3:** SSB Noise Figure measurements performed with a small-signal noise source, bandpass filter and 6dB matching pad on RF input, bandpass filter and 6dB matching pad on the LO input, and no other RF signals applied.

Note 2: The LTC5541 is guaranteed functional over the operating temperature range from -40°C to 85°C.

Note 4: LO switch isolation is measured at the IF output port at the IF frequency with fLO1 and fLO2 offset by 2MHz.

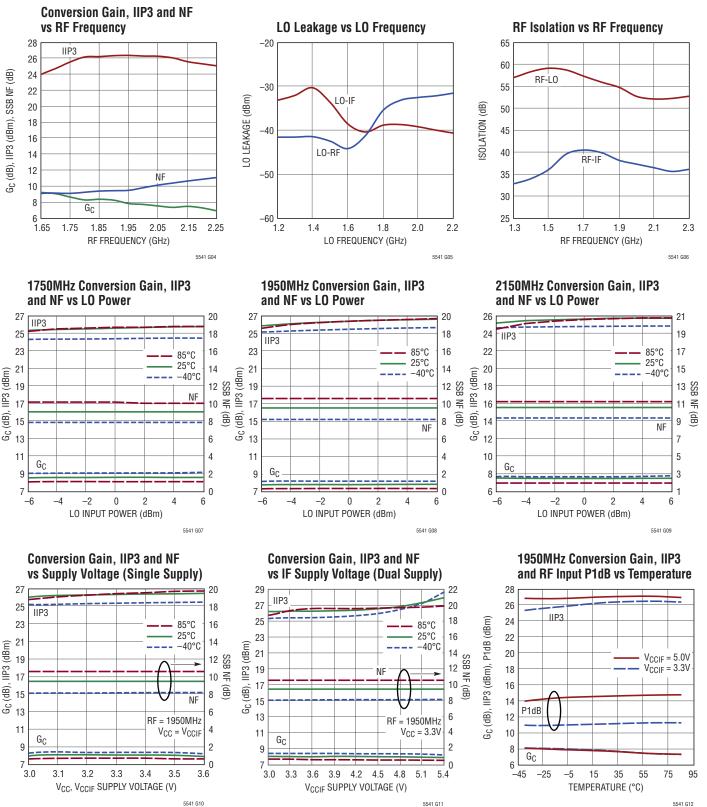
## **TYPICAL DC PERFORMANCE CHARACTERISTICS** SHDN = Low, Test circuit shown in Figure 1.





### TYPICAL AC PERFORMANCE CHARACTERISTICS Low-Side LO

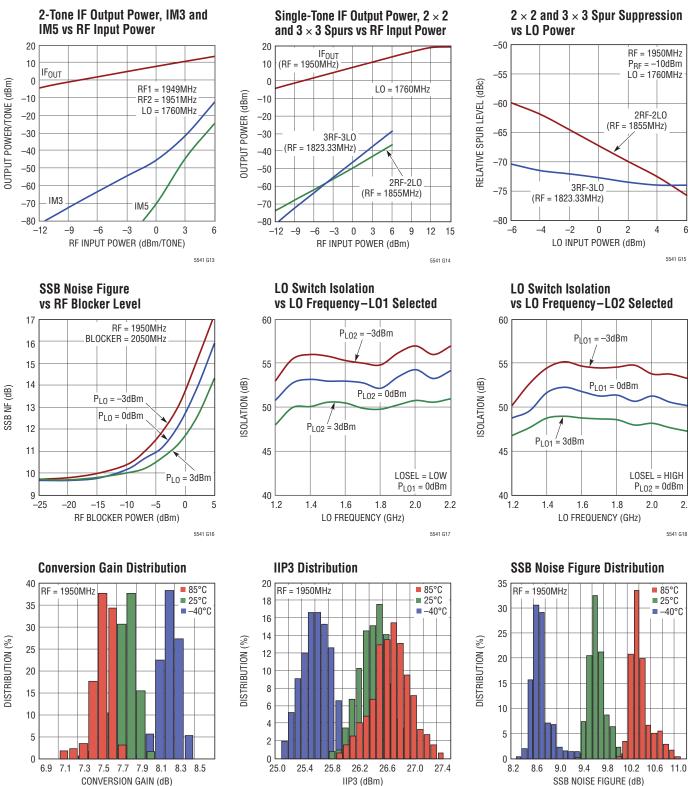
 $V_{CC} = 3.3V$ ,  $V_{CCIF} = 3.3V$ , SHDN = Low,  $T_A = 25^{\circ}C$ ,  $P_{LO} = 0dBm$ ,  $P_{RF} = -3dBm$  (-3dBm/tone for two-tone IIP3 tests,  $\Delta f = 2MHz$ ), IF = 190MHz, unless otherwise noted. Test circuit shown in Figure 1.

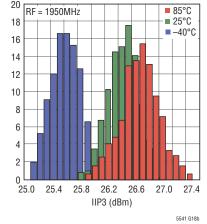




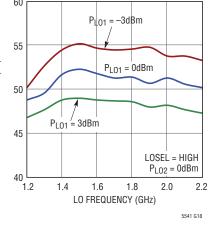
#### TYPICAL AC PERFORMANCE CHARACTERISTICS Low-Side LO (continued)

 $V_{CC} = 3.3V$ ,  $V_{CCIF} = 3.3V$ , SHDN = Low,  $T_A = 25^{\circ}C$ ,  $P_{LO} = 0dBm$ ,  $P_{RF} = -3dBm$  (-3dBm/tone for two-tone IIP3 tests,  $\Delta f = 2MHz$ ), IF = 190MHz, unless otherwise noted. Test circuit shown in Figure 1.



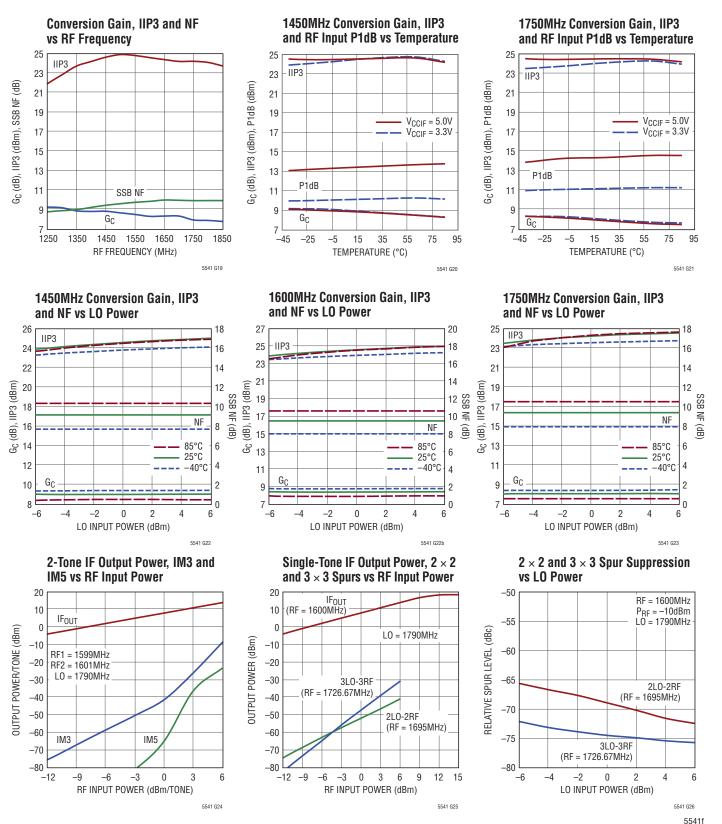


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**TYPICAL AC PERFORMANCE CHARACTERISTICS** High-Side L0 V<sub>CC</sub> = 3.3V, V<sub>CCIF</sub> = 3.3V, SHDN = Low, T<sub>A</sub> = 25°C, P<sub>LO</sub> = 0dBm, P<sub>RF</sub> = -3dBm (-3dBm/tone for two-tone IIP3 tests,  $\Delta f$  = 2MHz), IF = 190MHz, unless otherwise noted. Test circuit shown in Figure 1.





# PIN FUNCTIONS

**NC (Pin 1):** This pin is not connected internally. It can be left floating, connected to ground or to  $V_{CC}$ .

**RF (Pin 2):** Single-Ended Input for the RF Signal. This pin is internally connected to the primary side of the RF input transformer, which has low DC resistance to ground. **A series DC-blocking capacitor should be used to avoid damage to the integrated transformer.** The RF input is impedance matched, as long as the selected LO input is driven with a OdBm ±6dB source between 1.4GHz and 2GHz.

**CT (Pin 3):** RF Transformer Secondary Center-Tap. This pin may require a bypass capacitor to ground. See the Applications Information section. This pin has an internally generated bias voltage of 1.2V. It must be DC-isolated from ground and  $V_{CC}$ .

**GND (Pins 4, 10, 12, 13, 17, Exposed Pad Pin 21):** Ground. These pins must be soldered to the RF ground plane on the circuit board. The exposed pad metal of the package provides both electrical contact to ground and good thermal contact to the printed circuit board.

**SHDN (Pin 5):** Shutdown Pin. When the input voltage is less than 0.3V, the internal circuits supplied through pins 6, 8, 14, 18 and 19 are enabled. When the input voltage is greater than 3V, all circuits are disabled. Typical input current is less than  $10\mu$ A. This pin must not be allowed to float.

 $V_{CC2}$  (Pin 6) and  $V_{CC1}$  (Pin 8): Power Supply Pins for the LO Buffer and Bias Circuits. These pins are internally connected and must be externally connected to a regulated 3.3V supply, with bypass capacitors located close to the pin. Typical current consumption is 92mA. **LOBIAS (Pin 7):** This Pin Allows Adjustment of the LO Buffer Current. Typical DC voltage is 2.2V.

**LOSEL (Pin 9):** LO1/LO2 Select Pin. When the input voltage is less than 0.3V, the LO1 port is selected. When the input voltage is greater than 3V, the LO2 port is selected. Typical input current is  $11\mu$ A for LOSEL = 3.3V. This pin must not be allowed to float.

**LO1 (Pin 11) and LO2 (Pin 15):** Single-Ended Inputs for the Local Oscillators. These pins are internally biased at 0V and require external DC blocking capacitors. Both inputs are internally matched to  $50\Omega$ , even when the chip is disabled (SHDN = high).

 $V_{CC3}$  (Pin 14): Power Supply Pin for the LO Switch. This pin must be connected to a regulated 3.3V supply and bypassed to ground with a capacitor near the pin. Typical DC current consumption is less than 100µA.

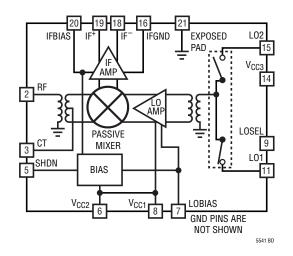
**IFGND (Pin 16):** DC Ground Return for the IF Amplifier. This pin must be connected to ground to complete the IF amplifier's DC current path. Typical DC current is 100mA.

**IF<sup>-</sup> (Pin 18) and IF<sup>+</sup> (Pin 19):** Open-Collector Differential Outputs for the IF Amplifier. These pins must be connected to a DC supply through impedance matching inductors, or a transformer center-tap. Typical DC current consumption is 50mA into each pin.

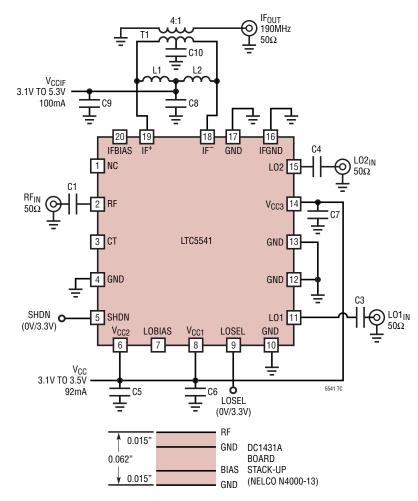
**IFBIAS (Pin20):** This Pin Allows Adjustment of the IFAmplifier Current. Typical DC voltage is 2.1V.



# **BLOCK DIAGRAM**



# **TEST CIRCUIT**



L1, L2 vs IF Frequencies		
L1, L2 (nH)		
270		
150		
100		
56		
33		

REF DES	VALUE	SIZE	COMMENTS
C1	2.2pF	0402	AVX
C3, C4, C6, C7, C8	22pF	0402	AVX
C5, C9	1µF	0603	AVX
C10	1000pF	0402	AVX
L1, L2	150nH	0603	Coilcraft 0603CS
T1 (Alternate)	TC4-1W-7ALN+ (WBC4-6TLB)		Mini-Circuits (Coilcraft)

Figure 1. Standard Downmixer Test Circuit Schematic (190MHz IF)



#### Introduction

The LTC5541 consists of a high linearity passive doublebalanced mixer core, IF buffer amplifier, high speed singlepole double-throw (SPDT) LO switch, LO buffer amplifier and bias/shutdown circuits. See Block Diagram section for a description of each pin function. The RF and LO inputs are single-ended. The IF output is differential. Low-side or high-side LO injection can be used. The evaluation circuit, shown in Figure 1, utilizes bandpass IF output matching and an IF transformer to realize a 50 $\Omega$  single-ended IF output. The evaluation board layout is shown in Figure 2.

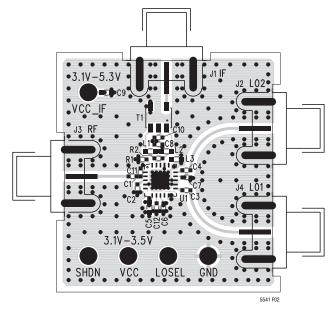


Figure 2. Evaluation Board Layout

### **RF** Input

The mixer's RF input, shown in Figure 3, is connected to the primary winding of an integrated transformer. A  $50\Omega$ match is realized when a series capacitor, C1, is connected to the RF input. C1 is also needed for DC blocking if the RF source has DC voltage present, since the primary side of the RF transformer is DC-grounded internally. The DC resistance of the primary is approximately  $3.6\Omega$ .

The secondary winding of the RF transformer is internally connected to the passive mixer. The center-tap of the transformer secondary is connected to pin 3 (CT) to allow the connection of bypass capacitor, C2. The value of C2 is LO frequency-dependent and is not required for most

applications. When used, C2 should be located within 2mm of pin 3 for proper high-frequency decoupling. The nominal DC voltage on the CT pin is 1.2V.

For the RF input to be matched, the selected LO input must be driven. A broadband input match is realized with C1 = 2.2 pF. The measured input return loss is shown in Figure 4 for LO frequencies of 1.4GHz, 1.75GHz and 2GHz. These LO frequencies correspond to the lower, middle and upper values of the LO range. As shown in Figure 4, the RF input impedance is somewhat dependent on LO frequency, although a single value of C1 is adequate to cover the 1.3GHz-2.3GHz RF band.

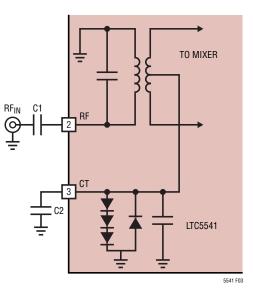


Figure 3. RF Input Schematic

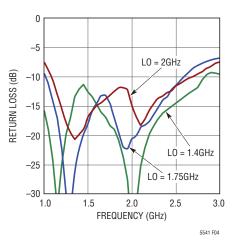


Figure 4. RF Input Return Loss



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The RF input impedance and input reflection coefficient, versus RF frequency, is listed in Table 1. The reference plane for this data is pin 2 of the IC, with no external matching, and the LO is driven at 1.75GHz.

FREQUENCY	INPUT	S	11
(GHz)	IMPEDANCE	MAG	ANGLE
1.0	24.1 + j42.1	0.58	92.1
1.2	33.1 + j47.2	0.53	79.8
1.4	43.6 + j49.2	0.47	69.7
1.6	58.0 + j47.1	0.41	56.9
1.8	50.2 + j20.6	0.20	77.8
2.0	43.0 + j32.4	0.34	82.9
2.2	43.7 + j37.8	0.39	79.0
2.4	44.1 + j44.4	0.43	72.4
2.6	49.0 + j51.7	0.47	63.6
2.8	56.8 + j57.6	0.48	55.0
3.0	68.9 + j61.0	0.48	45.7

Table 1. RF Input Impedance and S11
(at Pin 2, No External Matching, LO Input Driven at 1.75GHz)

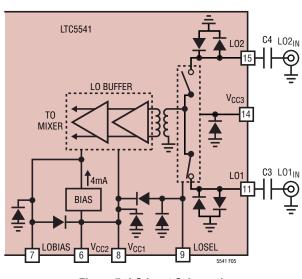
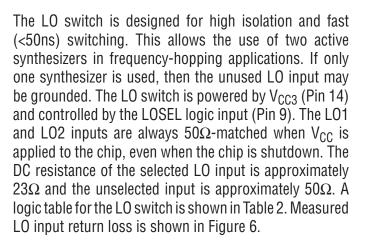


Figure 5. LO Input Schematic

#### LO Inputs

The mixer's LO input circuit, shown in Figure 5, consists of an integrated SPDT switch, a balun transformer, and a two-stage high-speed limiting differential amplifier to drive the mixer core. The LTC5541's LO amplifiers are optimized for the 1.4GHz to 2.0GHz LO frequency range. LO frequencies above or below this frequency range may be used with degraded performance.



#### Table 2. LO Switch Logic Table

LOSEL	ACTIVE LO INPUT
Low	L01
High	L02

The LO amplifiers are powered by  $V_{CC1}$  and  $V_{CC2}$  (pin 8 and pin 6). When the chip is enabled (SHDN = low), the internal bias circuit provides a regulated 4mA current to the amplifier's bias input, which in turn causes the amplifiers to draw approximately 80mA of DC current. This 4mA reference current is also connected to LOBIAS (Pin 7) to allow modification of the amplifier's DC bias current for special applications. The recommended application circuits require no LO amplifier bias modification, so this pin should be left open-circuited.

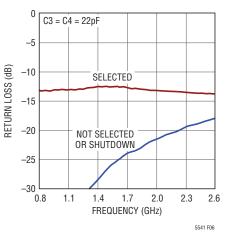


Figure 6. LO Input Return loss

The nominal LO input level is 0dBm although the limiting amplifiers will deliver excellent performance over a  $\pm$ 6dB input power range. LO input power greater than 6dBm may cause conduction of the internal ESD diodes. Series capacitors C3 and C4 optimize the input match and provide DC blocking.

The LO1 input impedance and input reflection coefficient, versus frequency, is shown in Table 3. The LO2 port is identical due to the symmetric device layout and packaging.

FREQUENCY	INPUT	5	<b>\$11</b>		
(GHz)	IMPEDANCE	MAG	ANGLE		
1.0	55.1 – j21.8	0.209	-65.2		
1.2	34.5 – j11.4	0.225	-135.9		
1.4	29.5 – j1.2	0.257	-176.1		
1.6	29.6 + j6.3	0.267	+158.2		
1.8	31.6 + j10.9	0.261	+141.5		
2.0	33.5 + j13.7	0.255	+130.7		
2.2	35.2 + j16.1	0.253	+121.6		
2.4	36.9 + j17.8	0.251	+114.4		
2.6	38.0 + j18.9	0.250	+110.0		
2.8	38.3 + j19.5	0.254	+108.3		
3.0	37.3 + j20.4	0.270	+108.5		

#### Table 3. LO1 Input Impedance vs Frequency (at Pin 11, No External Matching, LOSEL = Low)

### **IF Output**

The IF amplifier, shown in Figure 7, has differential opencollector outputs (IF<sup>+</sup> and IF<sup>-</sup>), a DC ground return pin (IFGND), and a pin for modifying the internal bias (IFBIAS). The IF outputs must be biased at the supply voltage ( $V_{CCIF}$ ), which is applied through matching inductors L1 and L2. Alternatively, the IF outputs can be biased through the center tap of a transformer. Each IF output pin draws approximately 50mA of DC supply current (100mA total). IFGND (pin 16) must be grounded or the amplifier will not draw DC current. Grounding through inductor L3 may improve LO-IF and RF-IF leakage performance in some applications, but is otherwise not necessary. High DC resistance in L3 will reduce the IF amplifier supply current, which will degrade RF performance.

For optimum single-ended performance, the differential IF outputs must be combined through an external IF

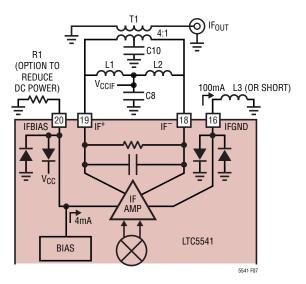


Figure 7. IF Amplifier Schematic with Bandpass Match

transformer or discrete IF balun circuit. The evaluation board (see Figures 1 and 2) uses a 4:1 ratio IF transformer for impedance transformation and differential to singleended transformation. It is also possible to eliminate the IF transformer and drive differential filters or amplifiers directly.

The IF output impedance can be modeled as  $300\Omega$  in parallel with 2.3pF at IF frequencies. An equivalent smallsignal model (including bondwire inductance) is shown in Figure 8. Frequency-dependent differential IF output impedance is listed in Table 4. This data is referenced to the package pins (with no external components) and includes the effects of IC and package parasitics.

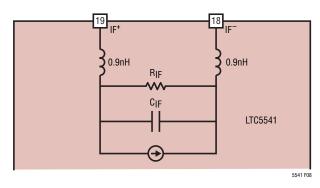


Figure 8. IF Output Small-Signal Model



#### **Bandpass IF Matching**

The IF output can be matched for IF frequencies as low as 90MHz or as high as 500MHz using the bandpass IF matching shown in Figure 1 and Figure 7. L1 and L2 resonate with the internal IF output capacitance at the desired IF frequency. The value of L1, L2 is calculated as follows:

L1, L2 =  $1/[(2 \pi f_{IF})^2 \cdot 2 \cdot C_{IF}]$ 

where C<sub>IF</sub> is the internal IF capacitance (listed in Table 4).

Values of L1 and L2 are tabulated in Figure 1 for various IF frequencies. For IF frequencies below 90MHz, the values of L1, L2 become unreasonably high and the lowpass topology shown in Figure 9 is preferred. Measured IF output return loss for bandpass IF matching is plotted in Figure 10.

	Table 4.	IF	Output	Impedance	vs	Frequency
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FREQUENCY (MHz)	DIFFERENTIAL OUTPUT IMPEDANCE (R <sub>IF</sub>    X <sub>IF</sub> (C <sub>IF</sub> ))		
90	329    -j769 (2.3pF)		
140	314    –j494 (2.3pF)		
190	305    −j364 (2.3pF)		
240	310    -j288 (2.3pF)		
300	303    –j226 (2.35pF)		
380	289    -j175 (2.4pF)		
500	273    –j118 (2.7pF)		

#### Lowpass IF Matching

An alternative IF matching network shown in Figure 9 uses a lowpass topology, which provides excellent RF to IF and LO to IF isolation.  $V_{CCIF}$  is supplied through the center tap of the 4:1 transformer. Similar to the bandpass topology, L1 and L2 cancel out the reactive part of the internal capacitance and the impedance transformation is realized by the 4:1 transformer. This topology is preferred for low IF frequencies since L1 and L2 may be replaced with shorts. The LTC5541 demo board (see Figure 2) has been laid out to accommodate this matching topology with very few modifications.

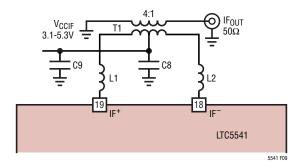


Figure 9. IF Output with Lowpass Matching

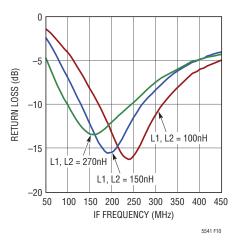


Figure 10. IF Output Return Loss

#### **IF Amplifier Bias**

The IF amplifier delivers excellent performance with  $V_{CCIF} = 3.3V$ , which allows the  $V_{CC}$  and  $V_{CCIF}$  supplies to be common. With  $V_{CCIF}$  increased to 5V, the RF input P1dB increases by approximately 3dB, at the expense of higher power consumption. Mixer performance at 1950MHz is shown in Table 5 with  $V_{CCIF} = 3.3V$  and 5V. For the highest conversion gain, high-Q wire-wound chip inductors are recommended for L1 and L2, especially when using  $V_{CCIF} = 3.3V$ . Low-cost multilayer chip inductors may be substituted, with a slight reduction in conversion gain.

Table 5. Performance Comparison with  $V_{CCIF}$  = 3.3V and 5V (RF = 1950MHz, Low-Side LO, IF = 190MHz)

V <sub>CCIF</sub>	I <sub>CCIF</sub> (mA)	G <sub>C</sub> (dB)	P1dB (dBm)	IIP3 (dBm)	NF (dB)
3.3V	100	7.8	11.3	26.4	9.6
5V	102	7.7	14.6	27.3	9.7



The IFBIAS pin (pin 20) is available for reducing the DC current consumption of the IF amplifier, at the expense of IIP3. This pin should be left open-circuited for optimum performance. The internal bias circuit produces a 4mA reference for the IF amplifier, which causes the amplifier to draw approximately 100mA. If resistor R1 is connected to pin 20 as shown in Figure 7, a portion of the reference current can be shunted to ground, resulting in reduced IF amplifier current. For example, R1 =  $1k\Omega$  will shunt away 1.5mA from pin 20 and the IF amplifier current will be reduced by 38% to approximately 62mA. The nominal, open-circuit DC voltage at pin 20 is 2.1V. Table 6 lists RF performance at 1950MHz versus IF amplifier current.

Table 6. Mixer Performance with Reduced IF Amplifier Current (RF = 1950MHz, Low-Side LO, IF = 190MHz)  $V_{CCIF} = 3.3V$ 

R1 (kΩ)	I <sub>CCIF</sub> (mA)	G <sub>C</sub> (dB)	IIP3 (dBm)	P1dB (dBm)	NF (dB)
OPEN	100	7.8	26.4	11.4	9.6
4.7	90	7.5	26.0	11.6	9.6
2.2	81	7.4	25.3	11.7	9.5
1	62	6.9	23.4	11.7	9.7
V <sub>CCIF</sub> = 5V					
R1 (kΩ)	I <sub>CCIF</sub> (mA)	G <sub>C</sub> (dB)	IIP3 (dBm)	P1dB (dBm)	NF (dB)
OPEN	102	7.7	27.3	14.6	9.7
4.7	92	7.5	27.2	14.7	9.6
2.2	83	7.2	26.5	14.8	9.6
1	65	6.7	24.7	14.0	9.7

#### Shutdown Interface

Figure 11 shows a simplified schematic of the SHDN pin interface. To disable the chip, the SHDN voltage must be higher than 3.0V. If the shutdown function is not required, the SHDN pin should be connected directly to GND. The voltage at the SHDN pin should never exceed the power supply voltage ( $V_{CC}$ ) by more than 0.3V. If this should occur, the supply current could be sourced through the ESD diode, potentially damaging the IC.

The SHDN pin must be pulled high or low. If left floating, then the on/off state of the IC will be indeterminate. If a three-state condition can exist at the SHDN pin, then a pull-up or pull-down resistor must be used.

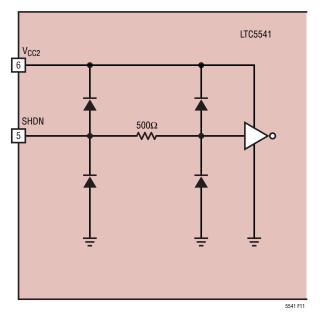


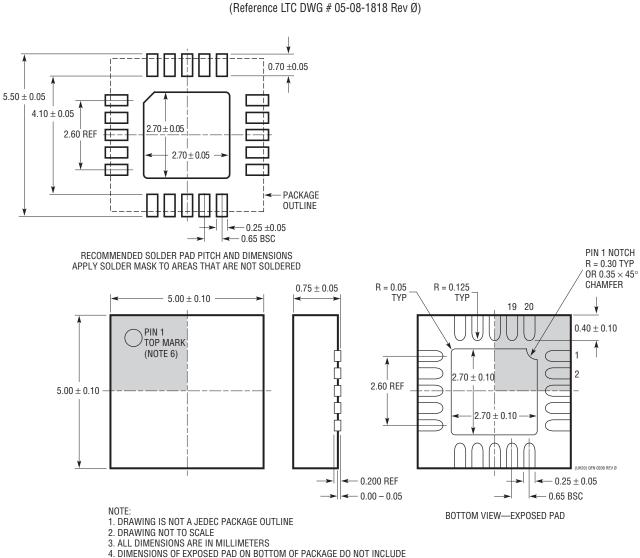
Figure 11. Shutdown Input Circuit

### **Supply Voltage Ramping**

Fast ramping of the supply voltage can cause a current glitch in the internal ESD protection circuits. Depending on the supply inductance, this could result in a supply voltage transient that exceeds the maximum rating. A supply voltage ramp time of greater than 1ms is recommended.



### PACKAGE DESCRIPTION



**UH Package** 20-Lead Plastic QFN (5mm × 5mm)

MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.20mm ON ANY SIDE 5. EXPOSED PAD SHALL BE SOLDER PLATED

6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION

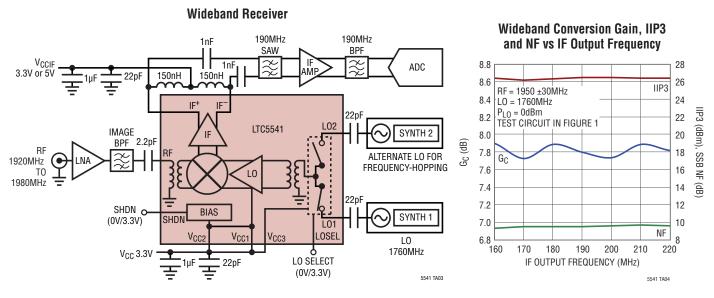
ON THE TOP AND BOTTOM OF PACKAGE

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5541f

# TYPICAL APPLICATION



# **RELATED PARTS**

PART NUMBER	DESCRIPTION	COMMENTS		
Infrastructure				
LT5527	400MHz to 3.7GHz, 5V Downconverting Mixer	2.3dB Conversion Gain, 23.5dBm IIP3 and 12.5dB NF at 1900MHz, 5V/78mA Supply		
LTC6400-X	300MHz Low Distortion IF Amp/ADC Driver	Fixed Gain of 8dB, 14dB, 20dB and 26dB; >36dBm OIP3 at 300MHz, Differential I/		
LTC6401-X	140MHz Low Distortion IF Amp/ADC Driver	Fixed Gain of 8dB, 14dB, 20dB and 26dB; >40dBm OIP3 at 140MHz, Differential I/O		
LTC6416	2GHz 16-Bit ADC Buffer	40.25dBm OIP3 to 300MHz, Programmable Fast Recovery Output Clamping		
LTC6412	31dB Linear Analog VGA	35dBm OIP3 at 240MHz, Continuous Gain Range –14dB to 17dB		
LT5554	Ultralow Distort IF Digital VGA	48dBm OIP3 at 200MHz, 2dB to 18dB Gain Range, 0.125dB Gain Steps		
LT5557	400MHz to 3.8GHz 3.3V Downconverting Mixer	2.9dB Conversion Gain, 24.7dBm IIP3 and 11.7dB NF at 1950MHz, 3.3V/82mA Supply		
LT5575	700MHz to 2.7GHz Direct Conversion I/Q Demodulator	Integrated Baluns, 28dBm IIP3, 13dBm P1dB, 0.03dB I/Q Amplitude Match, 0.4° Phase Match		
LT5578	400MHz to 2.7GHz High Linearty Upconverting Mixer	27dBm OIP3 at 900MHz, 24.2dBm at 1.95GHz, Integrated RF Transformer		
LT5579	1.5GHz to 3.8GHz High Linearity Upconverting Mixer	27.3dBm OIP3 at 2.14GHz, NF = 9.9dB, 3.3V Supply, Single-Ended LO and RF Ports		
LTC5598	5MHz to 1.6GHz I/Q Modulator	27.7dBm OIP3 at 140MHz, 22.9dBm at 900MHz, –161.2dBm/Hz Noise Floor		
<b>RF Power Detect</b>	ors			
LT5534	50MHz to 3GHz Log RF Power Detector with 60dB Dynamic Range	±1dB Output Variation over Temperature, 38ns Response Time, Log Linear Response		
LT5537	Wide Dynamic Range Log RF/IF Detector	Low Frequency to 1GHz, 83dB Log Linear Dynamic Range		
LT5570	2.7GHz Mean-Squared Detector	±0.5dB Accuracy Over Temperature and >50dB Dynamic Range, Fast 500ns Rise Time		
LT5581	6GHz Low Power RMS Detector	40dB Dynamic Range, ±1dB Accuracy Over Temperature, 1.5mA Supply Current		
ADCs	1			
LTC2208	16-Bit, 130Msps ADC	78dBFS Noise Floor, >83dB SFDR at 250MHz		
LTC2262-14	14-Bit, 150Msps ADC Ultralow Power at 1.8V Supply 72.8dB SNR, 88dB SFDR, 149mW Power Consumption			
LTC2242-12	12-Bit, 250Msps ADC	65.4dB SNR, 78dB SFDR, 740mW Power Consumption		



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